

STMAV340

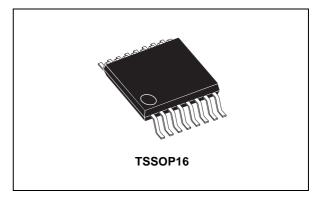
Low ON Resistance Quad, SPDT, Wide-Bandwidth Video Switch

Features

- Bi-directional operation
- 4 input/output channels analog video switch
- Wide bandwidth 300MHz
- Low 4Ω switch resistance between two ports
- Excellent R_{ON} matching between channels
- Minimal propagation delay through the switch
- Low quiescent current consumption
- V_{CC} Operating Range: 4.0V to 5.5V
- Zero bounce in flow-through mode
- Control inputs compatible with TTL level
- All input/output pins are on the same side facilitates PCB routing
- Data and control inputs provide the undershoot clamp diode
- Guaranteed break-before-make timing
- High ESD rating: > 2kV HBM
- -40°C to 85°C operating temperature range
- Suitable for both RGB and Composite-Video Switching
- Available in a small TSSOP16 package

Applications

- Advanced TVs
- Front projectors
- LCD Monitors
- Notebook PCs
- DVD Players



Description

The STMAV340 is a bidirectional quad (4 channel), high speed single pole/double throw (SPDT), low power CMOS TTL-compatible analog video switch designed for advanced video applications which demand superior image quality. The low ON Resistance (R_{ON}) of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

STMAV340 is designed for very low cross-talk, low bit-to-bit skew, high channel-to-channel noise isolation, and low I/O capacitance. The switch offers very little or practically no attenuation of the high speed signals at the outputs, thus preserving the signal integrity enough to pass stringent requirements.

The STMAV340 is able to simplify the PCB routing on inputs and outputs as well as reduce the overall BOM costs by eliminating the need for more costly input-output controllers.

Order Codes

Part Number	Part Number Temperature Range		Comments	
STMAV340	–40°C to +85°C	TSSOP16	STMAV340TTR	

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1 Summary Description

1.1 Functional Description

The STMAV340 is a high bandwidth, analog video switch. It is low ON-resistance and low I/O capacitance result in a very small propagation delay.

When OE_N is set to LOW, the select (S) pin connects port A to the selected port B or port C output. When OE_N is set to HIGH, the switch is OPEN and a high-impedance state exists between the A port and B/C ports.

Low differential gain and phase make this switch ideal for component and RGB video applications. This device has high bandwith and low crosstalk, making it ideal for high frequency applications as well.

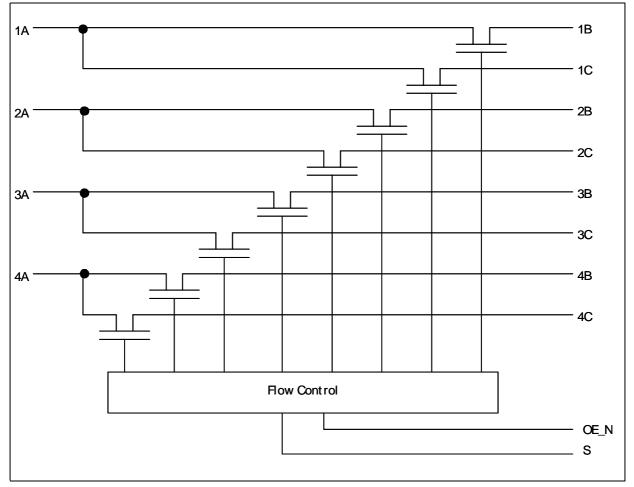


Figure 1. Functional Diagram



2 Pin Configuration

Figure	2.	Pin	Configuration	(Top	View	١
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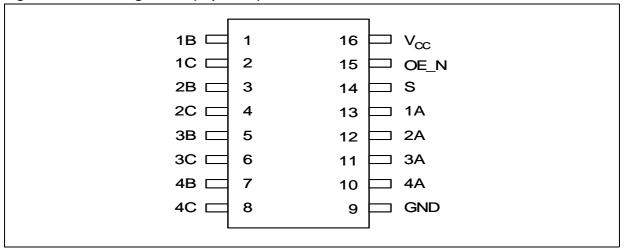


Table 1. Pin Description

Symbol	Туре	Name and Functions
OE_N	IN	Bus Switch Enable Note: 1
S	IN	Select Input
1A ,2A ,3A ,4A	IN/OUT	Port A; Analog Video I/Os
1B ,2B ,3B ,4B	IN/OUT	Bus B; Analog Video I/Os
1C, 2C, 3C, 4C	IN/OUT	Bus C; Analog Video I/Os
V _{CC}		Power supply
GND		Ground

Note: 1 Tie to V_{CC} through a pull-up resistor. The minimum value of the resistor is determined by the current-sinking capability of the driver.

Table 2. Truth Table

OE_N	S	ON Switch
0	0	1B,2B,3B,4B
0	1	1C,2C,3C,4C
1	Х	Disabled



3 Application Diagrams

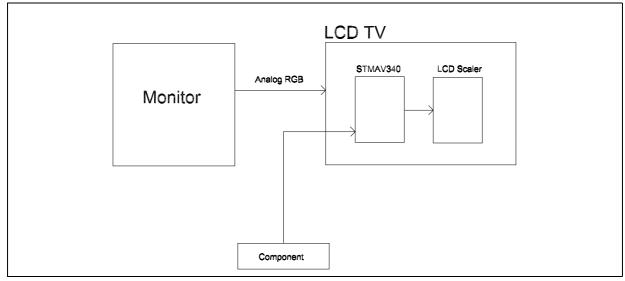
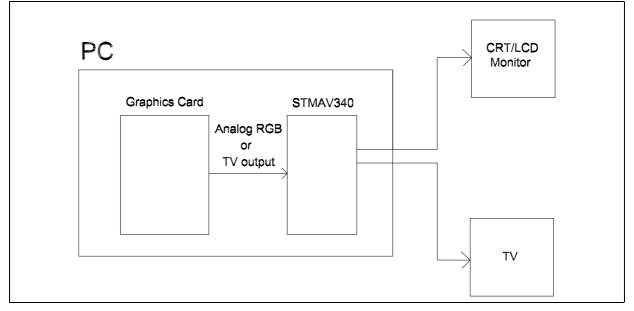


Figure 3. STMAV340 2-to-1 Analog Video Switch Used in an LCD TV





3.1 Power Supply Sequencing

Proper power-supply sequencing is advised for all CMOS devices. Applying V_{CC} before sending any signals to the input/output or control pins is recommended.



4 Maximum Ratings

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 3. Absolute Maximum Ratings

 $T_A = 25^{\circ}C$, GND= 0V

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage to Ground	-0.5 to + 7.0	V
V _S	DC Switch Voltage	-0.5 to + 7.0	V
V _{IN}	DC Input Voltage	-0.5 to + 7.0	V
I _{IK}	DC Input Diode Current	-50	mA
I _{OUT}	DC Output Sink Current	128	mA
I _{CC} /I _{GND}	DC V _{CC} /GND Current	±100	mA
T _{STG}	Storage Temperature Range	-65 to 150	°C

Note: Absolute maximum ratings are those values above which damage to the device may occur. Functional operation under these conditions is not implied. All voltages are referenced to GND.

5 Electrical Characteristics

Table 4. Recommended Operating Conditions

 $T_A = -20 \text{ to } +70^{\circ}\text{C}$

Symbol	Parameter (<i>Note: 1</i>)	Test Conditions	Min.	Тур.	Max.	Unit
V _{CC}	Power Supply Voltage		4.0		5.5	V
V _{IN}	Input Voltage		0		5.5	V
V _{OUT}	Output Voltage		0		5.5	V
t _{r,} t _f	Input Rise and Fall Time	Switch Control Input	0		5	ns/V
		Switch I/O	0		DC	ns/V
T _A	Free Air Operating Temperature		-40		+85	°C
V _{ESD}	ESD-Human Body Model (HMB) Note: 1		-2		+2	kV

Note: 1 Unused control inputs must be held HIGH or LOW. They should not float.

2 In accordance with IEC61000-4-2, level 4

Table 5. DC Electrical Characteristics

 $T_A = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Test Conditions	V _{CC} (V)	Min.	Тур.	Max.	Unit
	Analog Signal Range		5	0		2.0	V
V _{IK}	Clamp Diode Voltage	I _{IN} = -18mA	4.5			-1.2	V
V _{IH}	HIGH Level Input Voltage		4.0-5.5	2.0			V
V _{IL}	LOW Level Input Voltage		4.0-5.5			0.8	V
I	Input Leakage Current	$0 \le V_{IN} \le 5.5V$	5.5			±10	μΑ
I _{OFF}	OFF-STATE Leakage Current	$0 \le A, B \le V_{CC}, C \le V_{CC}$	5.5			±10	μA
R _{ON}	Switch ON resistance (1)	V _{IN} = 1.0V, I _{ON} = 13mA	4.5		3	7	Ω
		V _{IN} = 2.0V, I _{ON} = 26mA	4.5		7	10	Ω
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	5.5			3	μA
ΔI_{CC}	Increase in I _{CC} per Input	One input at 3.4V Other inputs at V _{CC} or GND	5.5			2.5	mA

Note: 1 Measured by the voltage drop between pin A and B/C pins at the indicated current through the switch. ON Resistance is determined by the lower of the voltages on the two (A or B/C) pins.



Table 6. AC Electrical Characteristics

 T_{A} = -40°C to +85°C, C_{L} = 20pF, RU = RD = 75 Ω

Symbol	Parameter	Test conditions	V _{CC} = 4.5 - 5.5V			$V_{CC} = 4.0V$		Unit
Cymbol	i alancici		Min.	Тур.	Max.	Min.	Max.	
t _{PZH} , t _{PZL}	Output Enable Time, Select to Bus B/C				5.2		5.7	ns
	Output Enable Time, OE_N to Bus A, B/C	V _I = OPEN for t _{PHZ}			5.1		5.6	ns
t _{PHZ} , t _{PLZ}	Output Disable Time, Select to Bus B/C	V _I = 7V for t _{PLZ}			5.2		5.5	ns
	Output Disable Time, Output Enable time OE_N to Bus A, B/C	V _I = OPEN for t _{PHZ}			5.5		5.5	ns
B _W	-3dB Bandwidth	R _L = 150Ω	300					MHz
		T _A = 25°C						
X _{TALK}	Crosstalk	R _{IN} = 10Ω		-58				dB
		R _L = 150Ω, 10 MHz						
D _G	Differential Gain	RL = 150Ω		0.64				%
		f = 3.58 MHz						
D _P	Differential Phase	RL = 150Ω		0.1				Deg.
		f = 3.58 MHz						
P _{IRR}	Off Isolation	RL = 150Ω		-60				dB
		10 MHz						

Table 7. Capacitance

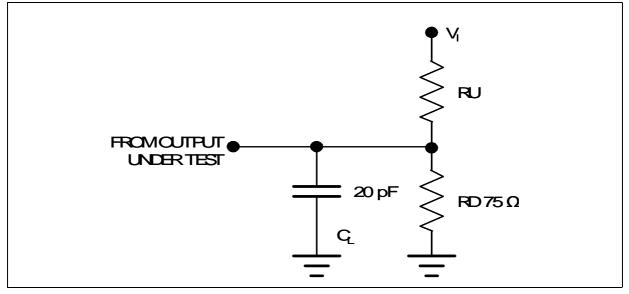
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 5.0V		3		pF
C _{I/O}	Input/Output Capacitance A Port	V _{CC}		7		pF
	Input/Output Capacitance B/C Port	OE_N = 5.0V		5		pF
C _{ON}	Switch On Capacitance	V _{CC} = 5.0V,		12		pF
		OE_N = 0.0V				



6 Test Circuit and Diagrams

All input pulses are supplied by generators having the following characteristics: PRR = 10MHz, $ZO = 50\Omega$, tr, tf = 2.5ns.

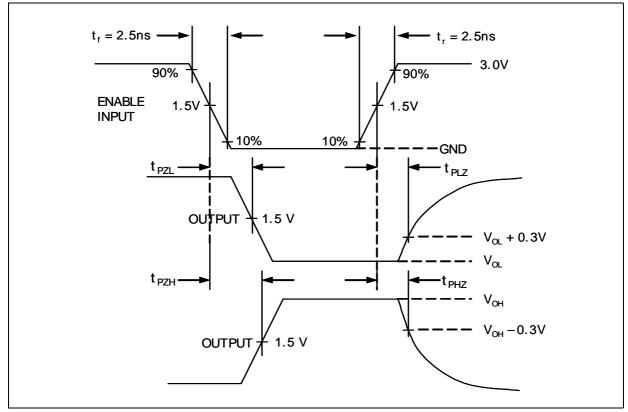
Figure 5. AC Test Circuit





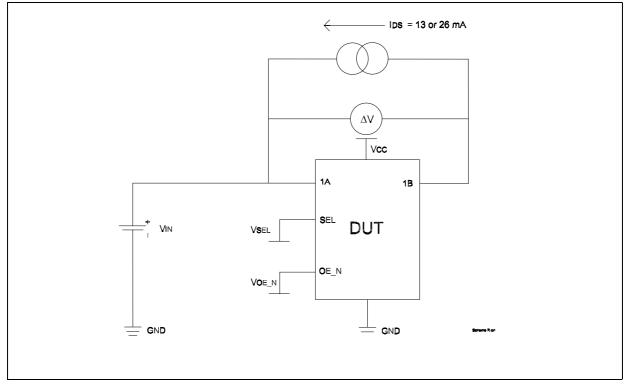
Note: CL includes probe and jig capacitance.

Figure 6. AC Waveforms





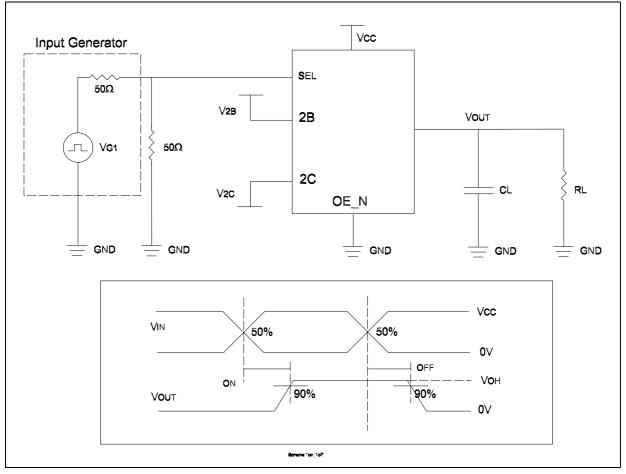




Test	V _{CC}	RL	CL	V _{2B}	V _{2C}
t _{ON}	4.75V ± 0.75V	75	20	GND	V _{CC}
	4.75V ± 0.75V	75	20	V _{CC}	GND
toff	4.75V ± 0.75V	75	20	GND	V _{CC}
	4.75V ± 0.75V	75	20	V _{CC}	GND

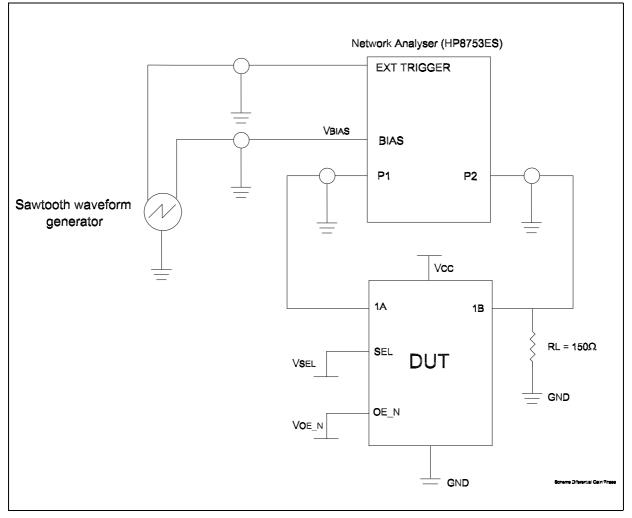
Table 8. Test Circuit

Figure 8. Turn-on/Turn-off Test Circuit and Timing Diagram



Differential gain and phase are measured at the output of the ON channel. For example, when $V_{SEL} = 0$, $V_{OE_N} = 0$ and 1A is the input, the output is measured at 1B.

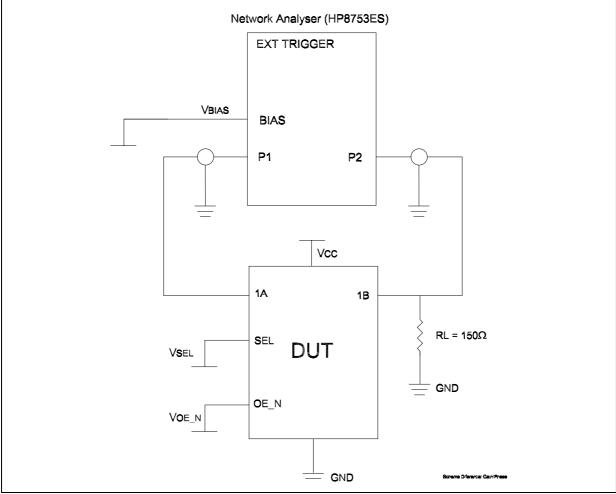






Frequency response is measured at the output of the ON channel. For example, when $V_{SEL} = 0$, $V_{OE_N} = 0$ and 1A is the input, the output is measured at 1B. All unused analog I/O ports are left open.

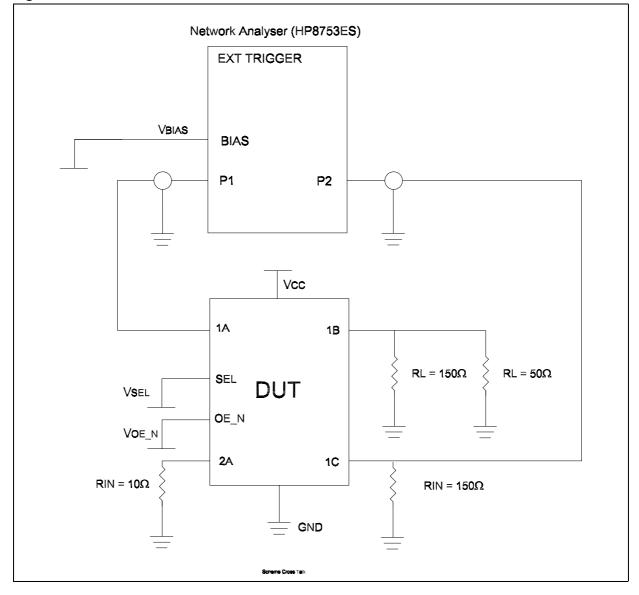






A 50 Ω termination resistor is needed for the network analyzer. Crosstalk is measured at the output of the non-adjacent ON channel. For example, V_{SEL} = 0, V_{OE_N} = 0, and 1A is the input, the output is measured at 1C. All unused analog input ports are connected to GND through IO-ports and the output ports are connected to GND through the 50 Ω pull down resistors.

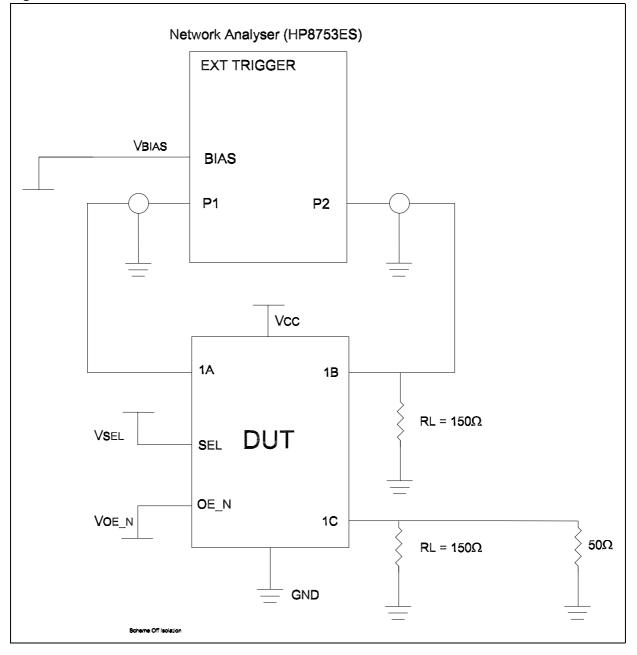
Figure 11. Crosstalk Test Circuit



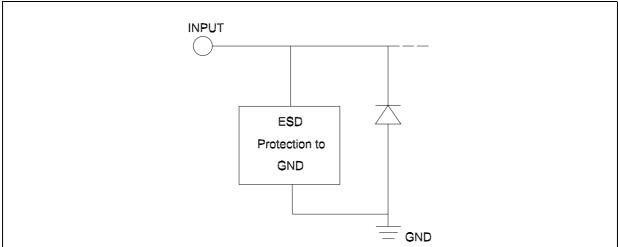
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A 50 Ω termination resistor is needed for the network analyzer. Off-isolation is measured at the output of the OFF channel. For example, when V_{SEL} = V_{CC}, V_{OE_N} = 0 and 1A is the input, the output is measured at 1B. All unsued analog input ports are left open, and the output ports are connected to GND through the 50 Ω pulldown resistors.

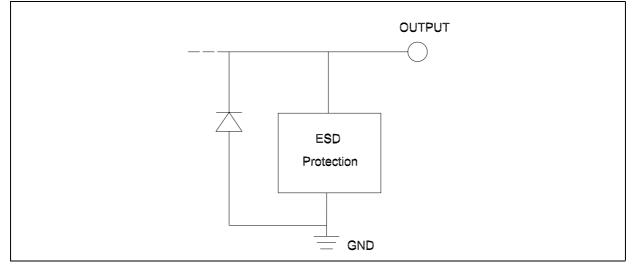
Figure 12. Off-Isolation Test Circuit



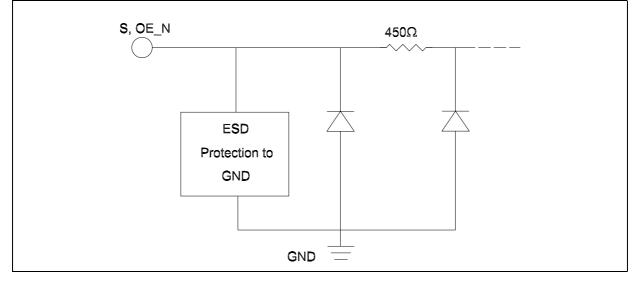












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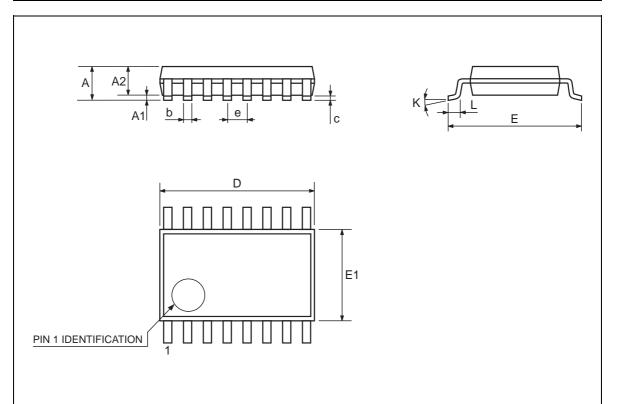
7 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



Figure 16. TSSOP16 Mechanical Data

	TSSOP16 MECHANICAL DATA								
DIM.		mm		inch					
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.			
А			1.1			0.433			
A1	0.05	0.10	0.15	0.002	0.004	0.006			
A2	0.85	0.9	0.95	0.335	0.354	0.374			
b	0.19		0.30	0.0075		0.0118			
С	0.09		0.20	0.0035		0.0079			
D	4.9	5	5.1	0.193	0.197	0.201			
E	6.25	6.4	6.5	0.246	0.252	0.256			
E1	4.3	4.4	4.48	0.169	0.173	0.176			
е		0.65 BSC			0.0256 BSC				
К	0°	4 [°]	8°	0 [°]	4 ⁰	8°			
L	0.50	0.60	0.70	0.020	0.024	0.028			



8 Revision History

Date	Revision	Description of Change
09-Sep-2005	1	First issue

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